

TCA9406 2ビット、双方向、1MHz、8kV HBM ESD I²CバスおよびSMBus電圧レベル・トランスレータ

1 特長

- I²CアプリケーションのSDAおよびSCLライン用の2ビット、双方向トランスレータ
- 方向ピンを必要としない双方向電圧レベル変換を提供
- OE = LOWまたはV_{CC} = 0V時に出力SCL_A、SDA_A、SCL_B、SDA_Bピンはハイ・インピーダンス
- すべてのSDAおよびSCLピンに内部10kΩプルアップ抵抗
- 1.65V~3.6V (Aポート)、2.3V~5.5V (Bポート) (V_{CCA} ≤ V_{CCB})
- V_{CC}絶縁機能: どちらかのV_{CC}入力がGNDレベルになると、両方のポートがハイ・インピーダンス状態になる
- 電源投入のシーケンス不要: V_{CCA}とV_{CCB}のいずれからでも立ち上げ可能
- 低I_{off}: V_{CCA}またはV_{CCB} = 0V時に2μA
- OE入力はV_{CCA}に直結、またはGPIOにより制御可能
- JESD 78、Class II準拠で100mA超のラッチアップ性能
- JESD 22を超えるESD保護
 - Aポート
 - 2500V、人体モデル(A114-B)
 - 250V、マシン・モデル(A115-A)
 - 1500V、デバイス帯電モデル(C101)
 - Bポート
 - 8kV、人体モデル(A114-B)
 - 250V、マシン・モデル(A115-A)
 - 1500V、デバイス帯電モデル(C101)

2 アプリケーション

- I²C/SMBus
- UART
- GPIO

3 概要

TCA9406は2ビット、双方向のI²CおよびSMBus電圧レベル・トランスレータで、出力イネーブル(OE)入力が搭載されています。AサイドではV_{CCA}を基準に1.65V~3.6V、BサイドではV_{CCB}を基準に2.3V~5.5Vで動作します。これによって、標準的な1.8V、2.5V、3.3V、5Vの電源レールのいずれについても、異なる信号レベル間でのインターフェイスが可能です。

OE入力ピンはV_{CCA}を基準とし、V_{CCA}に直結できますが、5.5Vも許容します。また、OEピンを制御してロジックLOWに設定すると、すべてのSCLおよびSDAピンをハイ・インピーダンス状態にすることができ、静止時消費電流が大幅に減少します。

通常のI²CおよびSMBus動作、または他のオープン・ドレイン構成において、TCA9406は最高2Mbpsをサポートするため、SCL周波数が100kHz (Standard-mode)、400kHz (Fast-mode)、1MHz (Fast-mode Plus)である標準のI²C速度と互換性があります。また、TCA9406は汎用レベル・トランスレータとしても使用でき、AおよびBサイドのポートが両方ともプッシュプル・デバイスで駆動される場合、最高24Mbpsに対応できます。

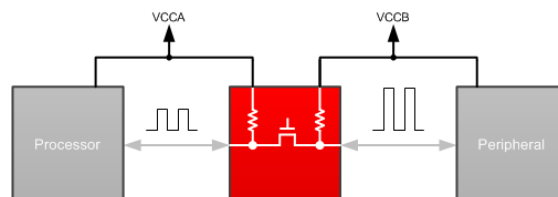
TCA9406は、SCL_A、SDA_A、SCL_B、SDA_Bに10kΩのプルアップ抵抗が内蔵されています。合計プルアップ抵抗を減らし、立ち上がりエッジを高速化するため、バスに外部プルアップ抵抗を追加することもできます。

製品情報⁽¹⁾

型番	パッケージ	本体サイズ(公称)
TCA9406	SM8 (8)	2.95mm×2.80mm
	US8 (8)	2.30mm×2.00mm
	DSBGA (8)	1.90mm×0.90mm

(1) 利用可能なすべてのパッケージについては、このデータシートの末尾にある注文情報を参照してください。

TCA9406の代表的なアプリケーション・ブロック図



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4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Revision F (October 2018) から Revision G に変更	Page
• Changed section title From: Pullup or Pulldown Resistors on I/O Lines To: Pullup Resistors on I/O Lines.....	20
• Deleted text "An external pull down..." and Equation 1 from the <i>Detailed Design Procedure</i> section.....	21
• Changed pin 1 From: To controller To: To system in 図 13	23
• Changed pin 5 From: To system To: To controller in 図 13	23

Revision E (August 2018) から Revision F に変更	Page
• Changed the <i>Functional Block Diagram</i>	18
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Revision D (July 2018) から Revision E に変更	Page
• Changed the new DSBGA pinout drawing From: Bottom View to: Top View.....	5

Revision C (December 2014) から Revision D に変更	Page
• Changed the updated pinout drawings.....	5
• Changed t_{dis} no external load MAX values From: 50 To: 200 ns in <i>Switching Characteristics</i> ($V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$).....	10
• Changed t_{dis} no external load MAX values From: 40 To: 200 ns in <i>Switching Characteristics</i> ($V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$).....	10
• Changed t_{dis} no external load MAX values From: 35 To: 200 ns in <i>Switching Characteristics</i> ($V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$).....	11
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- Changed the *Parameter Measurement Information* section..... 16

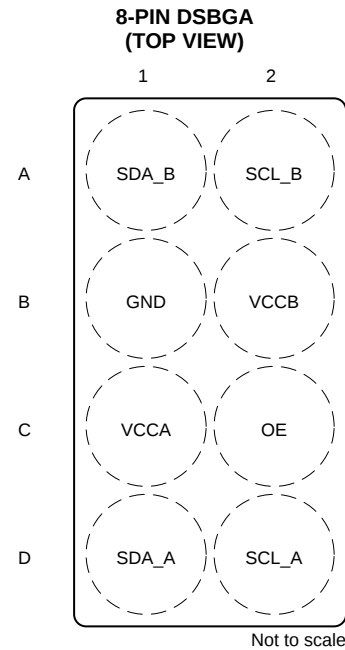
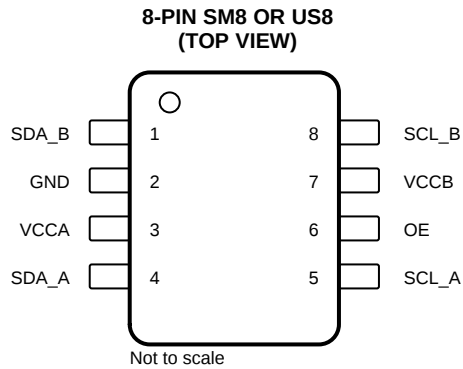
Revision B (June 2013) から Revision C に変更
Page

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- 「ピン構成および機能」セクション、「ESD定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクション 追加 [1](#)
-

Revision A (February 2013) から Revision B に変更
Page

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- 注文情報表を削除、この情報はPOAに移動 [1](#)
-

5 Pin Configuration and Functions



Pin Functions

PIN			TYPE	DESCRIPTION
NAME	DCT, DCU	YZP		
SDA_B	1	A1	I/O	Input/output B. Referenced to V_{CCB} .
GND	2	B1	GND	Ground
VCCA	3	C1	Power	A-port supply voltage. $1.65\text{ V} \leq V_{CCA} \leq 3.6\text{ V}$ and $V_{CCA} \leq V_{CCB}$
SDA_A	4	D1	I/O	Input/output A. Referenced to V_{CCA} .
SCL_A	5	D2	I/O	Input/output A. Referenced to V_{CCA} .
OE	6	C2	Input	Output enable (active High). Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
VCCB	7	B2	Power	B-port supply voltage. $2.3\text{ V} \leq V_{CCB} \leq 5.5\text{ V}$
SCL_B	8	A2	I/O	Input/output B. Referenced to V_{CCB} .

6 Specifications

6.1 Absolute Maximum Ratings⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA}	Supply voltage range		–0.5	4.6	V
V _{CCB}	Supply voltage range		–0.5	6.5	V
V _I	Input voltage range ⁽²⁾	A port	–0.5	4.6	V
		B port	–0.5	6.5	
V _O	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾	A port	–0.5	4.6	V
		B port	–0.5	6.5	
V _O	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾	A port	–0.5	V _{CCA} + 0.5	V
		B port	–0.5	V _{CCB} + 0.5	
I _{IK}	Input clamp current	V _I < 0		–50	mA
I _{OK}	Output clamp current	V _O < 0		–50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
T _{stg}	Storage temperature		–65	150	°C

- (1) Stresses beyond those listed under [Absolute Maximum Ratings](#) may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under [Recommended Operating Conditions](#) is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

6.2 ESD Ratings

			VALUE	UNIT	
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	A-Port	±2500	V
			B-Port	±8000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾		±1500	V
		Machine model (MM), A115-A		±250	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

V_{CCI} is the supply voltage associated with the input port. V_{CCO} is the supply voltage associated with the output port.

		V_{CCA}	V_{CCB}	MIN	MAX	UNIT	
V_{CCA}	Supply voltage ⁽¹⁾			1.65	3.6	V	
V_{CCB}	Supply voltage			2.3	5.5	V	
V_{IH}	High-level input voltage	A-port I/Os	1.65 V to 1.95 V	2.3 V to 5.5 V	$V_{CCI} - 0.2$	V_{CCI}	V
			2.3 V to 3.6 V		$V_{CCI} - 0.4$	V_{CCI}	
		B-port I/Os	1.65 V to 3.6 V	2.3 V to 5.5 V	$V_{CCI} - 0.4$	V_{CCI}	
		OE input			$V_{CCA} \times 0.65$	5.5	
$V_{IL}^{(2)}$	Low-level input voltage	A-port I/Os	1.65 V to 3.6 V	2.3 V to 5.5 V	0	0.15	V
		B-port I/Os			0	0.15	
		OE input			0	$V_{CCA} \times 0.35$	
$\Delta t/\Delta v$	Input transition rise or fall rate	A-port I/Os, push-pull driving	1.65 V to 3.6 V	2.3 V to 5.5 V		10	ns/V
		B-port I/Os, push-pull driving				10	
		Control input				10	
T_A	Operating free-air temperature			−40	85	°C	

(1) V_{CCA} must be less than or equal to V_{CCB} (except during power-on transient time), and V_{CCA} must not exceed 3.6 V.

(2) The maximum V_{IL} value is provided to ensure that a valid V_{OL} is maintained. The V_{OL} value is V_{IL} plus the voltage drop across the pass-gate transistor.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TCA9406			UNIT
		DCT	DCU	YZP	
		8 PINS	8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	182.6	199.1	105.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	113.3	72.4	1.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	94.9	77.8	10.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	39.4	6.2	3.1	°C/W
ψ_{JB}	Junction-to-board characterization parameter	93.9	77.4	10.8	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics⁽¹⁾⁽²⁾⁽³⁾

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	T _A = 25°C	−40°C to 85°C		UNIT
					TYP	MIN	MAX	
V _{OHA}		I _{OH} = −20 μA, V _{IB} ≥ V _{CCB} − 0.4 V	1.65 V to 3.6 V	2.3 V to 5.5 V	V _{CCA} × 0.67			V
V _{OLA}		I _{OL} = 1 mA, V _{IB} ≤ 0.15 V	1.65 V to 3.6 V	2.3 V to 5.5 V	0.4			V
V _{OHB}		I _{OH} = −20 μA, V _{IA} ≥ V _{CCA} − 0.2 V	1.65 V to 3.6 V	2.3 V to 5.5 V	V _{CCB} × 0.67			V
V _{OLB}		I _{OL} = 1 mA, V _{IA} ≤ 0.15 V	1.65 V to 3.6 V	2.3 V to 5.5 V	0.4			V
I _I	OE	V _I = V _{CCI} or GND	1.65 V to 3.6 V	2.3 V to 5.5 V	±1	±2		μA
I _{off}	A port		0 V	0 V to 5.5 V	±1	±2		μA
	B port		0 to 3.6 V	0 V	±1	±2		μA
I _{OZ}	A or B port	OE less than V _{IL}	1.65 V to 3.6 V	2.3 V to 5.5 V	±1	±2		μA
I _{CCA}		V _I = V _O = open, I _O = 0	1.65 V to V _{CCB}	2.3 V to 5.5 V	2.4			μA
			3.6 V	0 V	2.2			
			0 V	5.5 V	−1			
I _{CCB}		V _I = V _O = open, I _O = 0	1.65 V to V _{CCB}	2.3 V to 5.5 V	12			μA
			3.6 V	0 V	−1			
			0 V	5.5 V	1			
I _{CCA} + I _{CCB}		V _I = V _O = open, I _O = 0	1.65 V to V _{CCB}	2.3 V to 5.5 V	14.4			μA
C _I	OE		3.3 V	3.3 V	2.5	3.5		pF
C _{io}	A or B port		3.3 V	3.3 V	10			pF
	A port				5	6		
	B port				6	7.5		

- (1) V_{CCI} is the V_{CC} associated with the input port.
 (2) V_{CCO} is the V_{CC} associated with the output port.
 (3) V_{CCA} must be less than or equal to V_{CCB} , and V_{CCA} must not exceed 3.6 V.

6.6 Timing Requirements ($V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CCB} = 2.5 V ± 0.2 V						
Data rate	Push-pull driving			21		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	47		ns
	Open-drain driving			500		
V _{CC} = 3.3 V ± 0.3 V						
Data rate	Push-pull driving			22		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	45		ns
	Open-drain driving			500		
V _{CC} = 5 V ± 0.5 V						
Data rate	Push-pull driving			24		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	41		ns
	Open-drain driving			500		

6.7 Timing Requirements ($V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CCB} = 2.5 V ± 0.2 V						
Data rate	Push-pull driving			20		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	50		ns
	Open-drain driving			500		
V _{CC} = 3.3 V ± 0.3 V						
Data rate	Push-pull driving			22		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	45		ns
	Open-drain driving			500		
V _{CC} = 5 V ± 0.5 V						
Data rate	Push-pull driving			24		Mbps
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	41		ns
	Open-drain driving			500		

6.8 Timing Requirements ($V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CC} = 3.3 V ± 0.3 V						
Data rate	Push-pull driving			23	Mbps	
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	43	ns	
	Open-drain driving			500		
V _{CC} = 5 V ± 0.5 V						
Data rate	Push-pull driving			24	Mbps	
	Open-drain driving			2		
t _w Pulse duration	Push-pull driving		Data inputs	41	ns	
	Open-drain driving			500		

6.9 Switching Characteristics ($V_{CCA} = 1.8 \text{ V} \pm 0.15 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
V _{CCB} = 2.5 V ± 0.2 V						
t _{PHL}	A	B	Push-pull driving		5.3	ns
t _{PLH}			Open-drain driving	2.3	8.8	
			Push-pull driving		6.8	
			Open-drain driving		50	
t _{PHL}	B	A	Push-pull driving		4.4	ns
t _{PLH}			Open-drain driving	1.9	5.3	
			Push-pull driving		5.3	
			Open-drain driving		5.3	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		9.5	ns
			Open-drain driving	38	165	
t _{rB}	B-port rise time		Push-pull driving		10.8	ns
			Open-drain driving	34	145	
t _{fA}	A-port fall time		Push-pull driving		5.9	ns
			Open-drain driving		6.9	
t _{fB}	B-port fall time		Push-pull driving		13.8	
			Open-drain driving		13.8	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	21		Mbps
			Open-drain driving	2		
V _{CCB} = 3.3 V ± 0.3 V						
t _{PHL}	A	B	Push-pull driving		5.4	ns
t _{PLH}			Open-drain driving	2.4	9.6	
			Push-pull driving		7.1	
			Open-drain driving		40	
t _{PHL}	B	A	Push-pull driving		4.5	ns
t _{PLH}			Open-drain driving	1.1	4.4	
			Push-pull driving		4.5	
			Open-drain driving		4.5	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		9.3	ns
			Open-drain driving	30	132	
t _{rB}	B-port rise time		Push-pull driving		9.1	ns
			Open-drain driving	23	106	
t _{fA}	A-port fall time		Push-pull driving		6	ns
			Open-drain driving		6.4	
t _{fB}	B-port fall time		Push-pull driving		16.2	ns
			Open-drain driving		16.2	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	22		Mbps
			Open-drain driving	2		

Switching Characteristics ($V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$) (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
V _{CCB} = 5 V ± 0.5 V						
t _{PHL}	A	B	Push-pull driving		6.8	ns
t _{PLH}			Open-drain driving	2.6	10	
			Push-pull driving		7.5	
			Open-drain driving		33	
t _{PHL}	B	A	Push-pull driving		4.7	ns
t _{PLH}			Open-drain driving	1.2	4	
			Push-pull driving		0.5	
			Open-drain driving		0.5	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		7.6	ns
			Open-drain driving	22	95	
t _{rB}	B-port rise time		Push-pull driving		7.6	ns
			Open-drain driving	10	58	
t _{fA}	A-port fall time		Push-pull driving		13.3	ns
			Open-drain driving		6.1	
t _{fB}	B-port fall time		Push-pull driving		16.2	ns
			Open-drain driving		16.2	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	24		Mbps
			Open-drain driving	2		

6.10 Switching Characteristics ($V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
V _{CCB} = 2.5 V ± 0.2 V						
t _{PHL}	A	B	Push-pull driving		3.2	ns
			Open-drain driving	1.7	6.3	
t _{PLH}			Push-pull driving		3.5	
			Open-drain driving		3.5	
t _{PHL}	B	A	Push-pull driving		3	ns
			Open-drain driving	1.8	4.7	
t _{PLH}			Push-pull driving		2.5	
			Open-drain driving		2.5	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		7.4	ns
			Open-drain driving	34	149	
t _{rB}	B-port rise time		Push-pull driving		8.3	ns
			Open-drain driving	35	151	
t _{fA}	A-port fall time		Push-pull driving		5.7	ns
			Open-drain driving		6.9	
t _{fB}	B-port fall time		Push-pull driving		7.8	
			Open-drain driving		8.8	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	20		Mbps
			Open-drain driving	2		
V _{CCB} = 3.3 V ± 0.3 V						
t _{PHL}	A	B	Push-pull driving		3.7	ns
			Open-drain driving	2	6	
t _{PLH}			Push-pull driving		4.1	
			Open-drain driving		4.1	
t _{PHL}	B	A	Push-pull driving		3.6	ns
			Open-drain driving	2.6	4.2	
t _{PLH}			Push-pull driving		1.6	
			Open-drain driving		1.6	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		6.6	ns
			Open-drain driving	28	121	
t _{rB}	B-port rise time		Push-pull driving		7.2	ns
			Open-drain driving	24	112	
t _{fA}	A-port fall time		Push-pull driving		5.5	ns
			Open-drain driving		6.2	
t _{fB}	B-port fall time		Push-pull driving		6.7	ns
			Open-drain driving		9.4	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	22		Mbps
			Open-drain driving	2		

Switching Characteristics ($V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$) (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
V _{CCB} = 5 V ± 0.5 V						
t _{PHL}	A	B	Push-pull driving		3.8	ns
t _{PLH}			Open-drain driving	2.1	5.8	
			Push-pull driving		4.4	
			Open-drain driving		4.4	
t _{PHL}	B	A	Push-pull driving		4.3	ns
t _{PLH}			Open-drain driving	1.2	4	
			Push-pull driving		1	
			Open-drain driving		1	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		5.6	ns
			Open-drain driving	24	89	
t _{rB}	B-port rise time		Push-pull driving		6.1	ns
			Open-drain driving	12	64	
t _{fA}	A-port fall time		Push-pull driving		5.3	ns
			Open-drain driving		5.8	
t _{fB}	B-port fall time		Push-pull driving		6.6	ns
			Open-drain driving		10.4	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	24		Mbps
			Open-drain driving	2		

6.11 Switching Characteristics ($V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
V _{CCB} = 3.3 V ± 0.3 V						
t _{PHL}	A	B	Push-pull driving		2.4	ns
t _{PLH}			Open-drain driving	1.3	4.2	
			Push-pull driving		4.2	
			Open-drain driving		4.2	
t _{PHL}	B	A	Push-pull driving		2.5	ns
t _{PLH}			Open-drain driving	1	124	
			Push-pull driving		2.5	
			Open-drain driving		2.5	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		5.6	ns
			Open-drain driving	25	116	
t _{rB}	B-port rise time		Push-pull driving		6.4	ns
			Open-drain driving	26	116	
t _{fA}	A-port fall time		Push-pull driving		5.4	ns
			Open-drain driving		6.1	
t _{fB}	B-port fall time		Push-pull driving		7.4	ns
			Open-drain driving		7.6	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	23		Mbps
			Open-drain driving	2		
V _{CCB} = 5 V ± 0.5 V						
t _{PHL}	A	B	Push-pull driving		3.1	ns
t _{PLH}			Open-drain driving	1.4	4.6	
			Push-pull driving		4.4	
			Open-drain driving		4.4	
t _{PHL}	B	A	Push-pull driving		3.3	ns
t _{PLH}			Open-drain driving	1	97	
			Push-pull driving		2.6	
			Open-drain driving		2.6	
t _{en}	OE	A or B			200	ns
t _{dis}	OE	A or B	with external load		200	ns
			no external load		200	ns
t _{rA}	A-port rise time		Push-pull driving		4.8	ns
			Open-drain driving	19	85	
t _{rB}	B-port rise time		Push-pull driving		7.4	ns
			Open-drain driving	14	72	
t _{fA}	A-port fall time		Push-pull driving		5	ns
			Open-drain driving		5.7	
t _{fB}	B-port fall time		Push-pull driving		7.6	ns
			Open-drain driving		8.3	
t _{SK(O)}	Channel-to-channel skew				0.7	ns
Max data rate			Push-pull driving	24		Mbps
			Open-drain driving	2		

6.12 Typical Characteristics

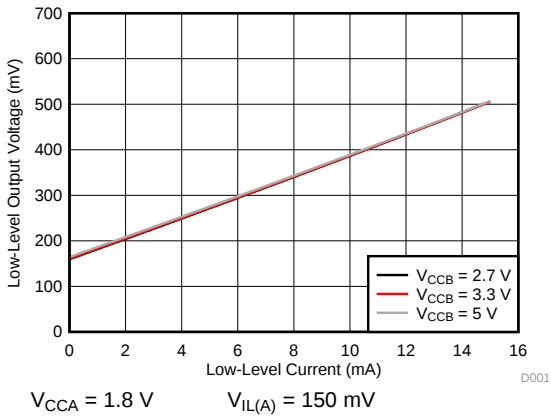


图 1. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

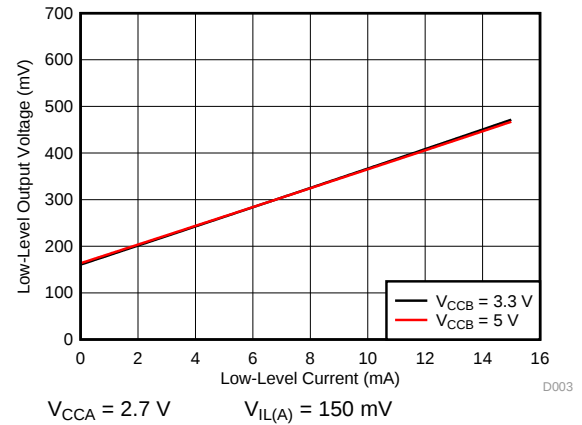


图 2. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

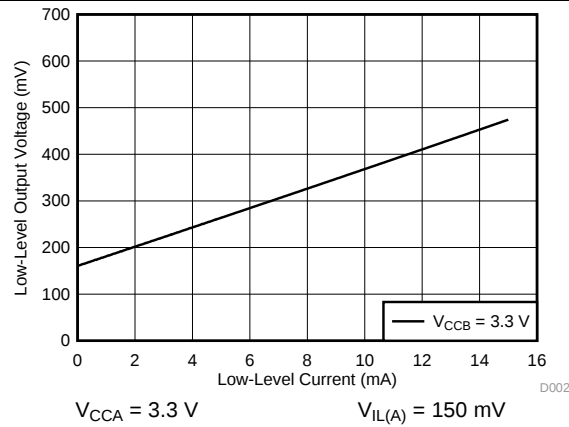
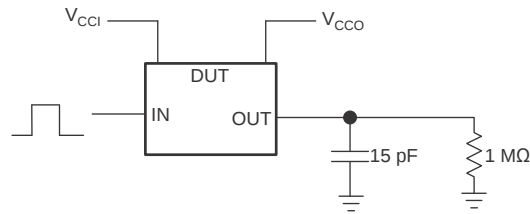
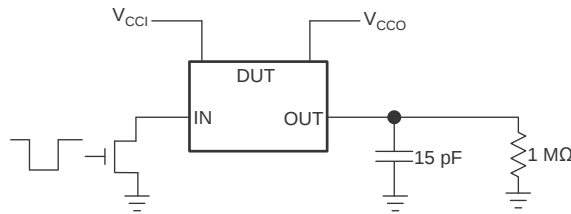


图 3. Low-Level Output Voltage ($V_{OL(Bx)}$) vs Low-Level Current ($I_{OL(Bx)}$)

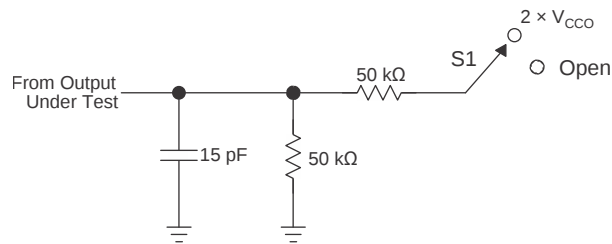
7 Parameter Measurement Information



✎ 4. Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Measurement Using a Push-Pull Driver



✎ 5. Data Rate, Pulse Duration, Propagation Delay, Output Rise-Time and Fall-Time Measurement Using an Open-Drain Driver



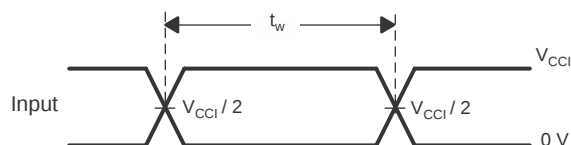
TEST	S1
t_{PLZ} / t_{PLZ}	$2 \times V_{CCO}$
t_{PHZ} / t_{PHZ}	Open

✎ 6. Load Circuit for Enable-Time and Disable-Time Measurement

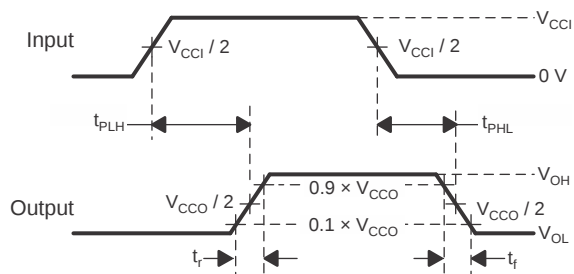
1. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
2. t_{PZL} and t_{PZH} are the same as t_{en} .
3. V_{CCI} is the V_{CC} associated with the input port.
4. V_{CCO} is the V_{CC} associated with the output port.

Parameter Measurement Information (continued)

7.1 Voltage Waveforms

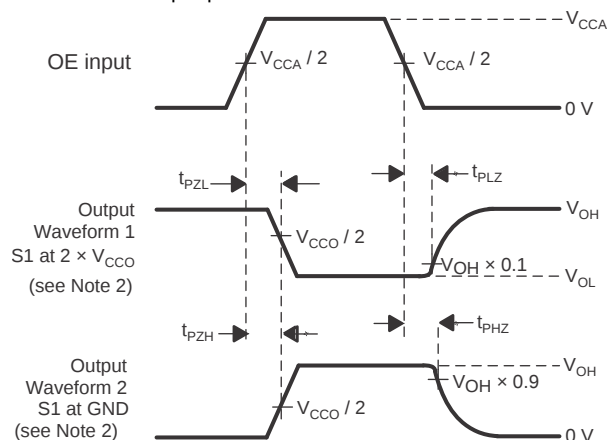


7. Pulse Duration



8. Propagation Delay Times

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 in 9 is for an output with internal such that the output is high, except when OE is high (see 6). Waveform 2 in 9 is for an output with conditions such that the output is low, except when OE is high.
- C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $dv/dt \geq 1 \text{ V/ns}$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.



9. Enable and Disable Times

Feature Description (continued)

These two bidirectional channels independently determine the direction of data flow without a direction-control signal. Each I/O pin is automatically reconfigured as either an input or an output, which is how this auto-direction feature is realized.

The TCA9406 is part of TI's "Switch" type voltage translator family and employs two key circuits to enable this voltage translation:

- 1) An N-channel pass-gate transistor topology that ties the A-port to the B-port
and
- 2) Output one-shot (O.S.) edge-rate accelerator circuitry to detect and accelerate rising edges on the A or B ports

For bidirectional voltage translation, pullup resistors are included on the device for dc current sourcing capability. The V_{GATE} gate bias of the N-channel pass transistor is set at approximately one threshold voltage (V_T) above the V_{CC} level of the low-voltage side. Data can flow in either direction without guidance from a control signal.

The O.S. rising-edge rate accelerator circuitry speeds up the output slew rate by monitoring the input edge for transitions, helping maintain the data rate through the device. During a low-to-high signal rising edge, the O.S. circuits turn on the PMOS transistors (T1, T2) to increase the current drive capability of the driver for approximately 30 ns or 95% of the input edge, whichever occurs first. This edge-rate acceleration provides high ac drive by bypassing the internal 10-k Ω pullup resistors during the low-to-high transition to speed up the signal. The output resistance of the driver is decreased to approximately 50 Ω to 70 Ω during this acceleration phase. To minimize dynamic I_{CC} and the possibility of signal contention, the user should wait for the O.S. circuit to turn off before applying a signal in the opposite direction. The worst-case duration is equal to the minimum pulse-width number provided in the [Timing Requirements](#) section of this data sheet.

8.3.2 Input Driver Requirements

The continuous dc-current "sinking" capability is determined by the external system-level open-drain (or push-pull) drivers that are interfaced to the TCA9406 I/O pins. Since the high bandwidth of these bidirectional I/O circuits is used to facilitate this fast change from an input to an output and an output to an input, they have a modest dc-current "sourcing" capability of hundreds of micro-Amps, as determined by the internal 10-k Ω pullup resistors.

The fall time (t_{fA} , t_{fB}) of a signal depends on the edge-rate and output impedance of the external device driving TCA9406 data I/Os, as well as the capacitive loading on the data lines.

Similarly, the t_{PHL} and max data rates also depend on the output impedance of the external driver. The values for t_{fA} , t_{fB} , t_{PHL} , and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50 Ω .

8.3.3 Output Load Considerations

TI recommends careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to best optimize trade-offs between dynamic ICC, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the TCA9406 output sees, so it is recommended that this lumped-load capacitance be considered to avoid O.S. re-triggering, bus contention, output signal oscillations, or other adverse system-level effects.

8.3.4 Enable and Disable

The TCA9406 has an OE input that is used to disable the device by setting OE low, which places all I/Os in the Hi-Z state. When TCA9406 is disabled, the internal pull up resistors are also disabled meaning if no external pull up resistors are present then the SDA/SCL lines will be left floating. The disable time (t_{dis}) indicates the delay between the time when OE goes low and when the outputs are disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Feature Description (continued)

8.3.5 Pullup Resistors on I/O Lines

Each A-port I/O has an internal 10-k Ω pullup resistor to V_{CCA} , and each B-port I/O has an internal 10-k Ω pullup resistor to V_{CCB} . If a smaller value of pullup resistor is required, an external resistor must be added from the I/O to V_{CCA} or V_{CCB} (in parallel with the internal 10-k Ω resistors). Adding lower value pullup resistors will effect V_{OL} levels, however. The internal pullups of the TCA9406 are disabled when the OE pin is low.

8.4 Device Functional Modes

The TCA9406 device has two functional modes, enabled and disabled. To disable the device set the OE input low, which places all I/Os in a high impedance state. Setting the OE input high will enable the device.

9 Application and Implementation

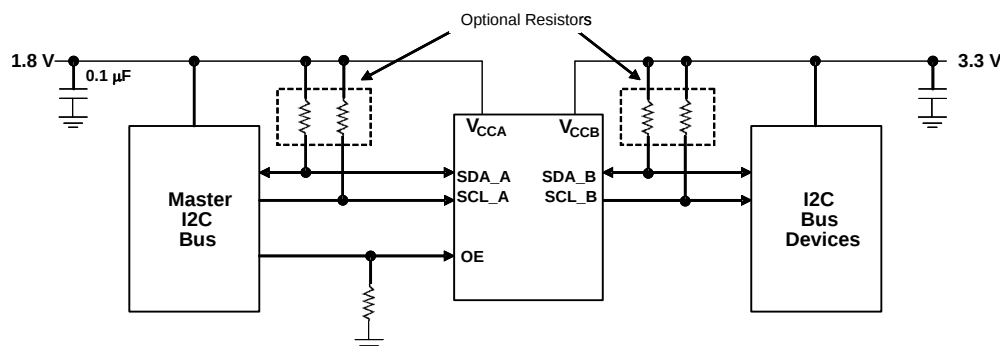
注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TCA9406 can be used to bridge the digital-switching compatibility gap between two voltage nodes to successfully interface logic threshold levels found in electronic systems. It should be used in a point-to-point topology for interfacing devices or systems operating at different interface voltages with one another. Its primary target application use is for interfacing with open-drain drivers on the data I/Os such as I²C or SMBus, where the data is bidirectional and no control signal is available.

9.2 Typical Application



Design Notes: OE can be tied directly to 1.8 V (V_{CCA}) to always be in ENABLE mode.

图 11. Typical Application Circuit

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 1. And make sure the $V_{CCA} \leq V_{CCB}$.

表 1. Design Parameters

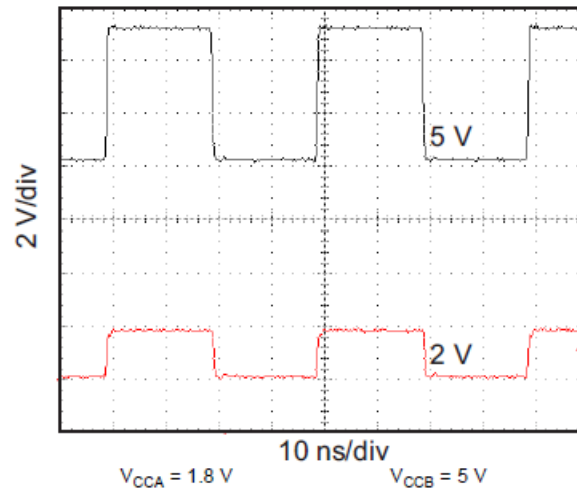
DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.65 to 3.6 V
Output voltage range	2.3 to 5.5 V

9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the TCA9406 device to determine the input voltage range. For a valid logic high the value must exceed the V_{IH} of the input port. For a valid logic low the value must be less than the V_{IL} of the input port.
- Output voltage range
 - Use the supply voltage of the device that the TCA9406 device is driving to determine the output voltage range
 - The TCA9406 device has 10-k Ω internal pullup resistors. External pullup resistors can be added to reduce the total RC of a signal trace if necessary.

9.2.3 Application Curve



✎ 12. Level-Translation of a 2.5-MHz Signal

10 Power Supply Recommendations

During operation, ensure that $V_{CCA} \leq V_{CCB}$ at all times. The sequencing of each power supply will not damage the device during the power up operation, so either power supply can be ramped up first. The output-enable (OE) input circuit is designed so that it is supplied by V_{CCA} and when the (OE) input is low, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the OE input pin must be tied to GND through a pulldown resistor and must not be enabled until V_{CCA} and V_{CCB} are fully ramped and stable. The minimum value of the pulldown resistor to ground is determined by the current-sourcing capability of the driver.

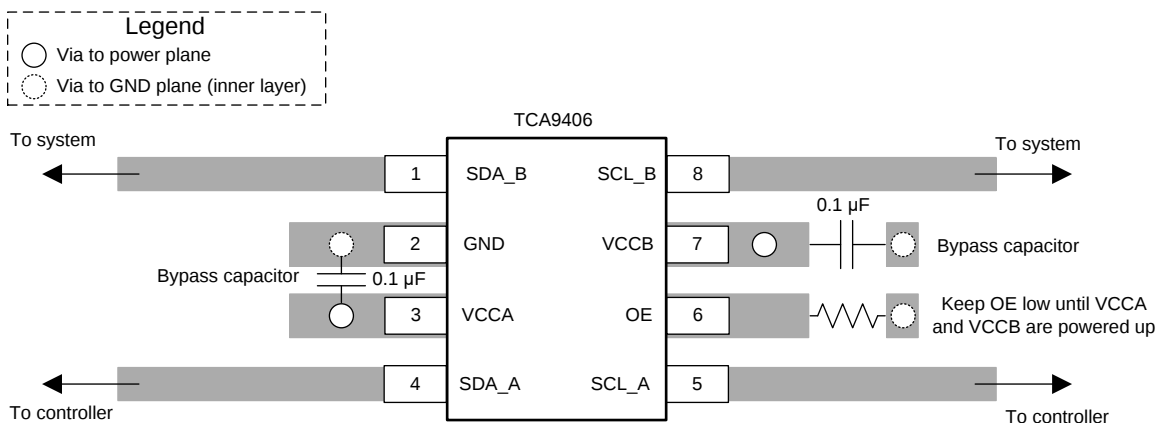
11 Layout

11.1 Layout Guidelines

To ensure reliability of the device, the following common printed-circuit board layout guidelines are recommended:

- Bypass capacitors should be used on power supplies and should be placed as close as possible to the V_{CCA} , V_{CCB} pin, and G_{ND} pin.
- Short trace lengths should be used to avoid excessive loading.
- PCB signal trace-lengths must be kept short enough so that the round-trip delay of any reflection is less than the one-shot duration, approximately 30 ns, ensuring that any reflection encounters low impedance at the source driver.

11.2 Layout Example



✎ 13. TCA9406 Layout Example

12 デバイスおよびドキュメントのサポート

12.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

12.2 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

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設計サポート *TIの設計サポート* 役に立つE2Eフォーラムや、設計サポート・ツールをすばやく見つけることができます。技術サポート用の連絡先情報も参照できます。

12.3 商標

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12.4 静電気放電に関する注意事項



すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。

静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TCA9406DCTR	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-40 to 85	NF9 (R, Z)
TCA9406DCTR.B	Active	Production	SSOP (DCT) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	NF9 (R, Z)
TCA9406DCUR	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	(F9, NF9R) NZ
TCA9406DCUR.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	(F9, NF9R) NZ
TCA9406DCURG4.B	Active	Production	VSSOP (DCU) 8	3000 LARGE T&R	-	Call TI	Call TI	-40 to 85	
TCA9406YZPR	Active	Production	DSBGA (YZP) 8	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	7W
TCA9406YZPR.B	Active	Production	DSBGA (YZP) 8	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	7W

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCA9406DCTR	SSOP	DCT	8	3000	180.0	13.0	3.35	4.5	1.55	4.0	12.0	Q3
TCA9406DCUR	VSSOP	DCU	8	3000	180.0	9.0	2.25	3.4	1.0	4.0	8.0	Q3
TCA9406YZPR	DSBGA	YZP	8	3000	180.0	8.4	1.11	2.1	0.56	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

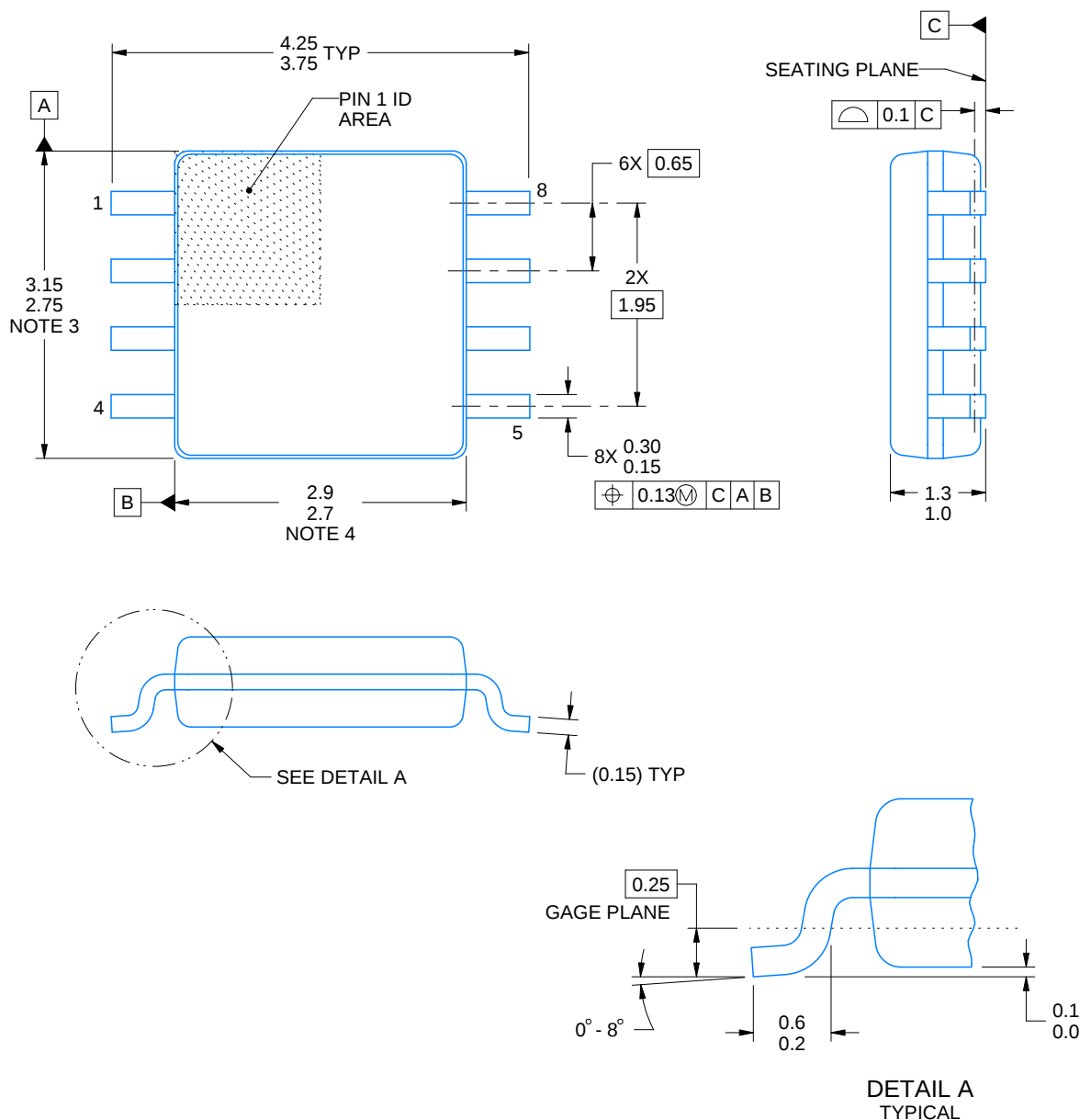
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCA9406DCTR	SSOP	DCT	8	3000	182.0	182.0	20.0
TCA9406DCUR	VSSOP	DCU	8	3000	182.0	182.0	20.0
TCA9406YZPR	DSBGA	YZP	8	3000	182.0	182.0	20.0



PACKAGE OUTLINE

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



4220784/C 06/2021

NOTES:

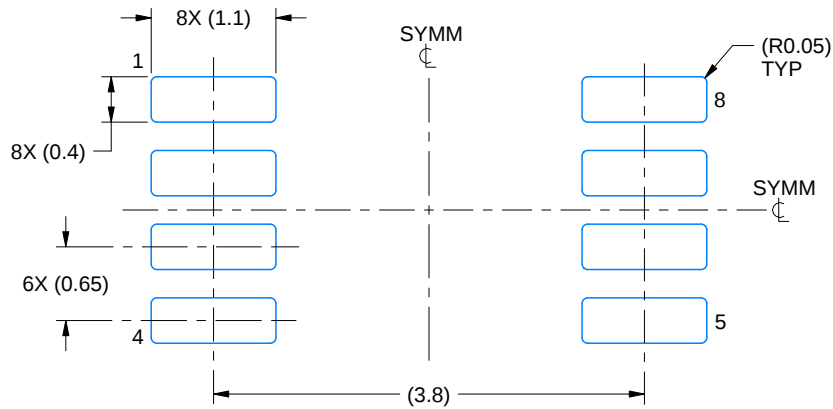
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.

EXAMPLE BOARD LAYOUT

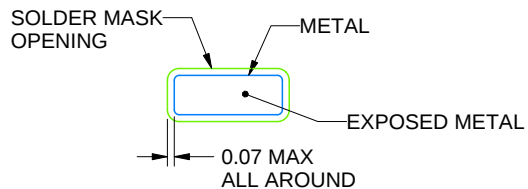
DCT0008A

SSOP - 1.3 mm max height

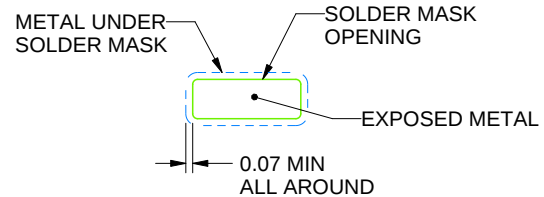
SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



NON SOLDER MASK
DEFINED



SOLDER MASK
DEFINED

SOLDER MASK DETAILS

4220784/C 06/2021

NOTES: (continued)

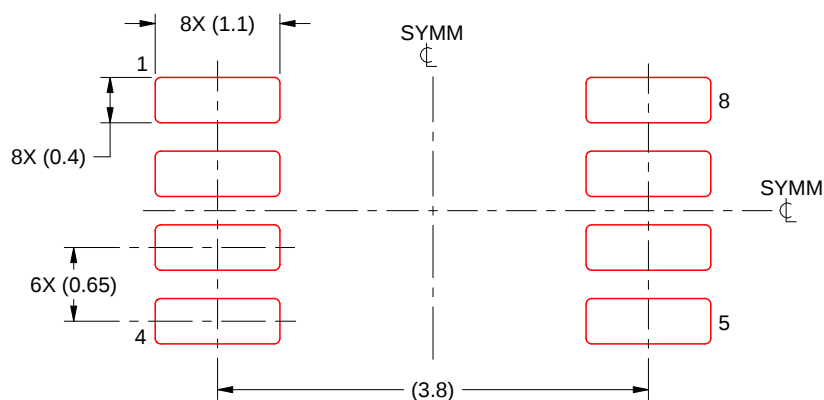
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCT0008A

SSOP - 1.3 mm max height

SMALL OUTLINE PACKAGE



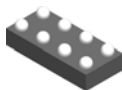
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4220784/C 06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

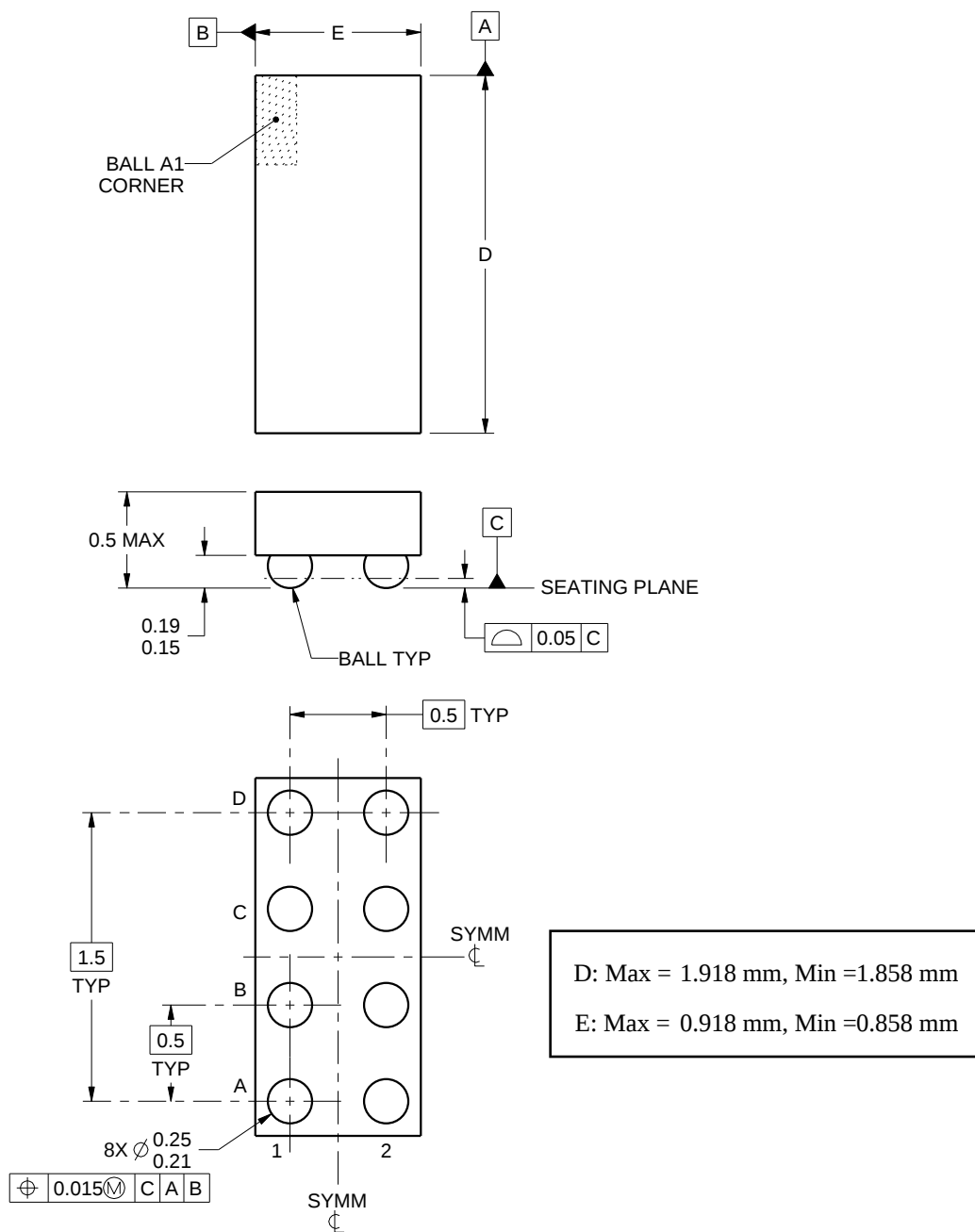
YZP0008



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



4223082/A 07/2016

NOTES:

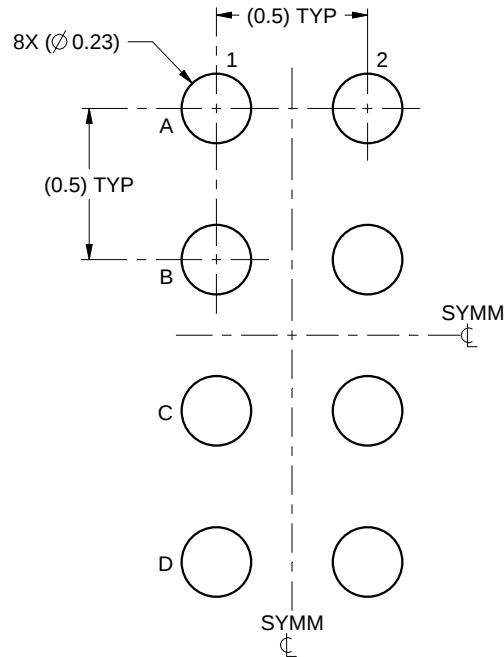
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

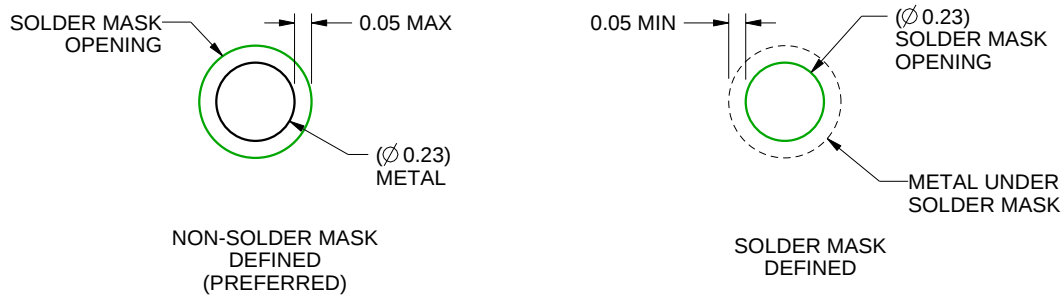
YZP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:40X



SOLDER MASK DETAILS
NOT TO SCALE

4223082/A 07/2016

NOTES: (continued)

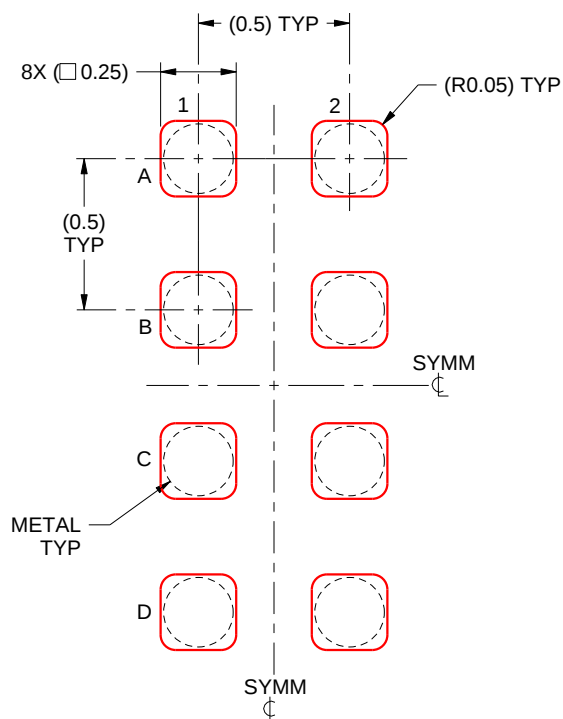
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

EXAMPLE STENCIL DESIGN

YZP0008

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4223082/A 07/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



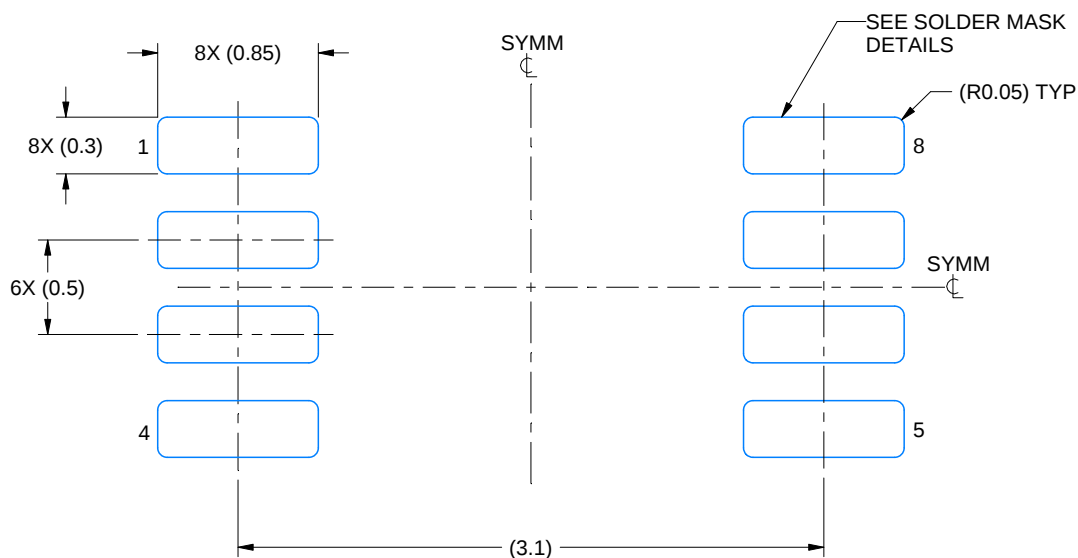
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-187 variation CA.

EXAMPLE BOARD LAYOUT

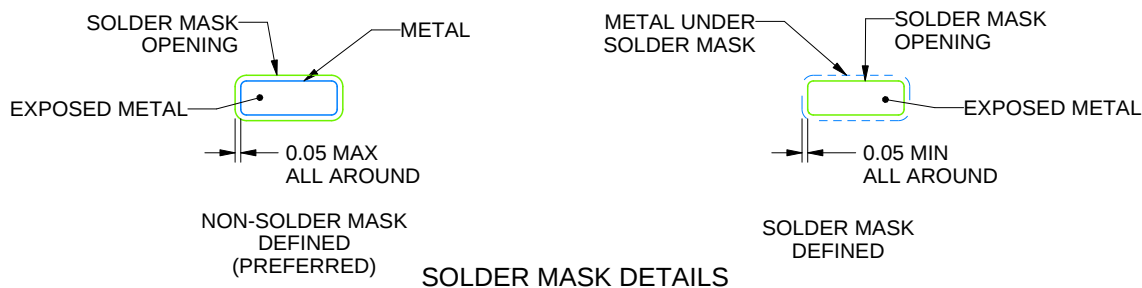
DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X



4225266/A 09/2014

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

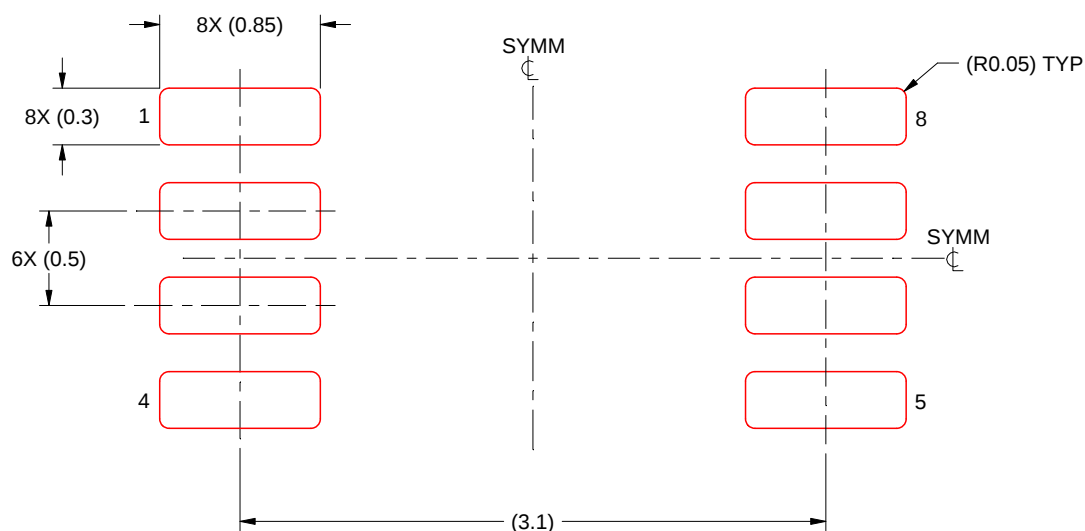
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DCU0008A

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A 09/2014

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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